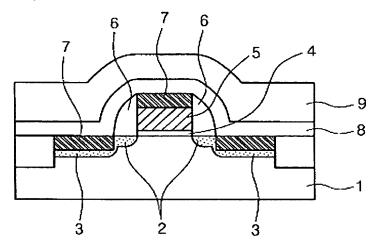
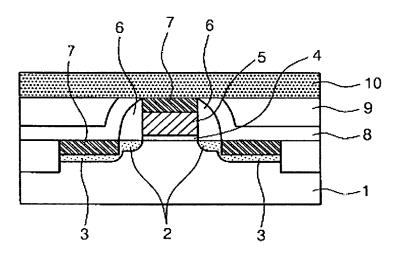
Inventor: Yungpil KIM
Title: "Method of Making a MOS Transistor"
Docket No. 20063/10004

Fig.1a



-- PRIOR ART --

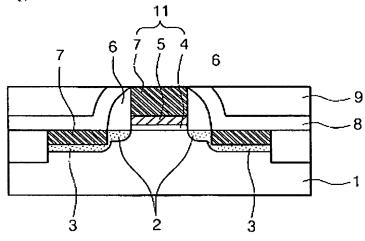
Fig.1b



-- PRIOR ART --

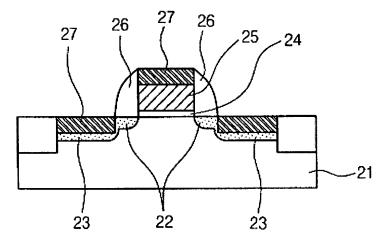
Inventor: Yungpil KIM
Title: "Method of Making a MOS Transistor"
Docket No. 20063/10004

Fig.1c



-- PRIOR ART --

Fig.2a



Inventor: Yungpil KIM
Title: "Method of Making a MOS Transistor"
Docket No. 20063/10004

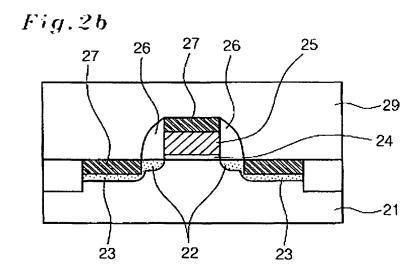


Fig.2e

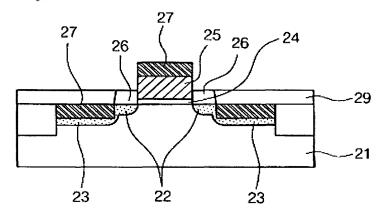
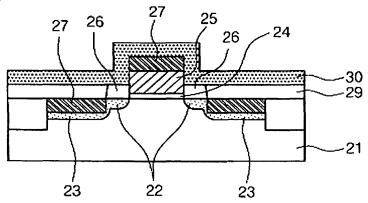


Fig.2d



Inventor: Yungpil KIM
Title: "Method of Making a MOS Transistor"
Docket No. 20063/10004

